# The Silicon Vertex Detector of the Belle II Experiment

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### Abstract

The Silicon Vertex Detector (SVD) is a part of the vertex detector in the Belle II experiment at the SuperKEKB collider (KEK, Japan). Since the start of data taking in spring 2019, the SVD has been operating stably and reliably with a high signal-to-noise ratio and hit efficiency, achieving good spatial resolution and high track reconstruction efficiency. The hit occupancy, which mostly comes from the beam-related background, is currently about 0.5% in the innermost layer, causing no impact on the SVD performance. In anticipation of the operation at higher luminosity in the next years, two strategies to sustain the tracking performance in future high beam background conditions have been developed and tested on data. One is to reduce the number of signal waveform samples to decrease dead time, data size, and occupancy. The other is to utilize the good hit-time resolution to reject the beam background hits. We also measured the radiation effects on the sensor current, strip noise, and full depletion voltage caused during the first two and a half years of operation. The results show no detrimental effect on the SVD performance.

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Keywords: Silicon strip detector, Vertex detector, Tracking detector, Belle II

### 1. Introduction

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The Belle II experiment [1] aims to probe new physics beyond the Standard Model in high-luminosity e<sup>+</sup>e<sup>-</sup> collisions at the SuperKEKB collider (KEK, Japan) [2]. SuperKEKB consists of the following components: injector LINAC, positron damping ring, and main storage ring with the electron and positron beamlines. The Belle II detector is located at the interaction point (IP) of the two beamlines. The main collision energy in the center-of-mass system is 10.58 GeV on the  $\Upsilon(4S)$ resonance, which enables various physics programs based on the large samples of B mesons,  $\tau$  leptons, and D mesons. Also, the asymmetric energy of the 7 GeV electron beam and 4 GeV positron beam is adopted for time-dependent *CP* violation measurements. The target of SuperKEKB is to accumulate an integrated luminosity of 50 ab<sup>-1</sup> with peak luminosity of about

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<sup>16</sup>  $6 \times 10^{35}$  cm<sup>-2</sup>s<sup>-1</sup>. In June 2021, SuperKEKB recorded the <sup>56</sup> wolrd's highest instantaneous luminosity of  $3.1 \times 10^{34}$  cm<sup>-2</sup>s<sup>-1</sup>. <sup>57</sup> <sup>18</sup> The data accumulated before July 2021 corresponds to an inte- <sup>58</sup> <sup>19</sup> grated luminosity of 213 fb<sup>-1</sup>. <sup>59</sup>

The Vertex Detector (VXD) is the innermost detector in the 60 20 Belle II detector system. The VXD has six layers: the inner 61 21 two layers (layers 1 and 2) are the Pixel Detector (PXD), and 62 22 the outer four layers (layers 3 to 6) are the Silicon Vertex De- 63 23 tector (SVD). The schematic cross-sectional view of the VXD 64 24 is shown in Fig. 1. The PXD consists of DEPFET pixel sen- 65 25 sors, and its innermost radius is 1.4 cm from the IP. A detailed 66 26 description of the SVD appears in Sec. 2. 27

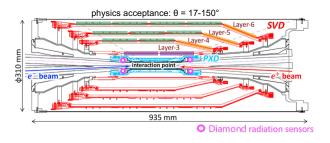


Figure 1: Schematic cross-sectional view of the VXD. The SVD is in red, the PXD in light-blue, and the IP beam pipe diamonds in pink circles. The locations of the three types of DSSDs are indicated by boxes in three colors: purple for small sensors, green for large sensors, and orange for trapezoidal sensors as described in Tab. 1.

Besides the VXD, diamond sensors [3] are mounted on the 71 28 IP beam pipe and the bellows pipes outside of the VXD. The 72 29 pink circles in Fig. 1 indicate the locations of the diamond sen-73 30 sors on the IP beam pipe. They measure the dose rates in these 74 31 locations. The measured doses are used to estimate the dose in 75 32 the SVD. They also send beam abort requests to SuperKEKB if 76 33 the radiation level gets too high to avoid severe damage to the 77 34 detector. 78 35

## 26 2. Belle II Silicon Vertex Detector

The SVD is crucial for extrapolating the tracks to the PXD. 82 37 This task is essential for measuring the decay vertices with the 83 38 PXD and pointing at a region-of-interest limiting the PXD read- 84 39 out volume. Other roles of the SVD are the standalone track re- 85 40 construction of low-momentum charged particles and their par- 86 41 ticle identification using ionization energy deposits. The SVD 87 42 also plays a critical role in the decay vertex measurement in the 88 43 case of long-lived particles like K<sub>S</sub> mesons, which decay inside 89 44 the SVD volume. 45

The SVD [4] consists of four layers of double-sided silicon 91 strip detectors (DSSDs). The material budget of the SVD is 92 47 about 0.7% of a radiation length per layer. The aluminum read- 93 48 out strips are AC-coupled to every other n/p-side strips (elec- 94 49 trodes) on the n-type substrate over the silicon oxide layer. On 95 50 each DSSD plane, a local coordinate is defined with u and v: 96 51 u-axis along n-side strips and v-axis perpendicular to u-axis. 97 52 In other words, p-side strips and n-side strips provide u and v 98 53 information, respectively. In the cylindrical coordinate, u corre- 99 54 sponds to  $r-\varphi$  information and v corresponds to z information.<sup>100</sup> 55

The SVD consists of three types of sensors: "small" sensors in layer 3, "large" sensors in the barrel region of layers 4, 5, and 6, and "trapezoidal" sensors in the forward region of layers 4, 5, and 6, which is slanted. They are indicated in blue, green, and orange boxes in Fig. 1. The dimensions for these three types of sensors are summarized in Tab. 1. The sensors are manufactured by two companies: the small and large sensors by Hamamatsu and trapezoidal sensors by Micron. The full depletion voltage is 60 V for Hamamatsu sensors and 20 V for Micron sensors; both types of sensors are operated at 100 V. In total, 172 sensors are assembled, corresponding to a total sensor area of 1.2 m<sup>2</sup> and approximately 224,000 readout strips.

	Small	Large	Trapezoidal
No. of u/p-strips	768	768	768
u/p-strip pitch	50 µm	75 µm	50–75 µm
No. of v/n-strips	768	512	512
v/n-strip pitch	160 µm	240 µm	240 µm
Thickness	320 µm	300 µm	300 µm
Manufacturer	Hamamatsu		Micron

Table 1: Table of the dimensions for the three types of sensors. Only readout strips are taken into account for number of strips and strip pitch.

The front-end ASIC used in the SVD is APV25 [5], which was originally developed for the CMS silicon tracker. The APV25 is radiation hard for a dose up to 100 Mrad radiation. It has 128 channel inputs and shapers for each channel with a shaping time of about 50 ns. For the SVD, the APV25 is operated in "multi-peak" mode. The mechanism of the data sampling in the multi-peak mode is explained in Fig. 2. The chip samples the height of the signal waveform with the 32 MHz clock (31 ns period) and stores each sample's information in an analog ring buffer. Since the bunch-crossing frequency is eight times faster than the sampling clock, the stored samples are not synchronous to the beam collision, in contrast to CMS, which motivates operation in the multi-peak mode. In the present readout configuration (the six-samples mode), at every reception of the Belle II global Level-1 trigger, the chip reads out six successive samples of the signal waveform stored in the buffers. The six-samples mode offers enough time window  $(6 \times 31 \text{ ns} = 187 \text{ ns})$  to accommodate large timing shifts of the trigger. In preparation for operation with higher luminosity, where background occupancy, trigger dead-time, and the data size increase, we developed the three/six-mixed acquisition mode (mixed-mode). The mixed-mode is a new method to read out the signal samples from the APV25, in which the number of the samples changes between three and six in each event, depending on the timing precision of each Level-1 trigger signal in that event. For triggers with good timing precision, three-samples data are read out and the data have half time window and half data size compared to ones of six-samples data, resulting in the reduction of the effect due to higher luminosity. This functionality was already implemented in the running system and confirmed by a few hours of smooth physics datataking. Before we start to use the mixed-mode, the effect on the performance due to the change of the acquisition mode is to be

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assessed. As the first step, the effect in the hit efficiency was132 101 evaluated as described in Sec. 3. 102 133

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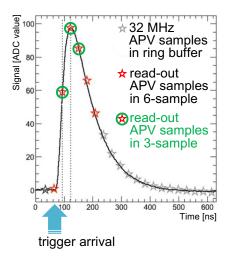


Figure 2: Example of sampling in the "multi-peak" mode of APV25. The black line shows the signal waveform after the CR-RC shaper circuit. The stars show the sampled signal height recorded in the analog ring buffer according to the 32 MHz sampling clock. The red stars indicate the six successive samples read out at the trigger reception in the six-samples mode. The red stars with a green circle indicate the samples read out in the three-samples acquisition.

The APV25 chips are mounted on each middle sensor (chip-103 on-sensor concept) with thermal isolation foam in between. 104 The merit of this concept is shorter signal propagation length, 105 leading to smaller capacitance of the signal line and hence re-106 duced noise level. To minimize the material budget the APV25 107 chips on the sensor are thinned down to 100 µm. APV25s are 108 mounted on a single side of the sensor and readout of the signals 109 is from the other side via wrapped flexible printed circuits. The 110 power consumption of the APV25 chip is 0.4 W/chip and in to-146 111 tal 700 W in the entire SVD. The chips are chilled by bi-phase<sub>147</sub> 112 -20°C CO<sub>2</sub>. 113 148

#### 3. Performance 114

The SVD was combined with the PXD to complete the VXD<sup>152</sup> 115 assembly in October 2018, and the VXD was installed to the 116 154 Belle II detector system in November 2018. Since March 2019, 117 155 the SVD has been operating reliably and smoothly for two and 118 a half years, without any major problems. The total fraction of <sup>156</sup> 119 masked strips is about 1%. There was only one issue where one 120 APV25 chip (out of 1,748 chips) was disabled during the spring 121 159 of 2019, which was remediated by reconnecting a cable in the 122 160 summer of 2019. 123

The SVD has also demonstrated stable and excellent perfor-<sup>161</sup> 124 mance [6]. The hit efficiency is continuously over 99% in most<sup>162</sup> 125 of the sensors. The cluster charge distributions are also reason-126 able. On the u/p-side, the most probable values agree with the<sup>164</sup> 127 calculated charge amount induced by MIPs within the uncer-128 tainty in calibration. On the v/n-side, 10-30% of the collected 129 charge is lost compared to MIP due to the smaller inter-strip 130 capacitance of the floating strips with larger strip pitches than 131

the u/p-side. The most probable values of the cluster signal-tonoise ratio distributions range from 13 to 30.

We measured the cluster position resolution by analyzing the  $e^+e^- \rightarrow \mu^+\mu^-$  data [7]. The cluster position resolution is es-135 timated from the residual between the cluster position and the track position not biased by the target cluster after subtracting the effect of the track extrapolation error. The cluster position 138 resolutions for different incident angles are shown in Fig. 3. For normal incident tracks, it agrees with the expectations from the 140 strip pitch including floating strips. For tracks with an incident angle, it is expected to get a better resolution, which is indeed 142 the case in the v/n-side results. However, this effect is not observed on the u/p-side, and the study is still ongoing to improve the cluster position estimation. 145

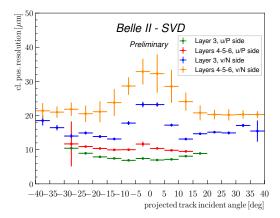


Figure 3: The SVD cluster position resolution depending on the projected track incident angle. The green (blue) plot shows the resolution in the u/p-side (n/vside) of layer-3 sensors, and the red (yellow) one shows the u/p-side (n/v-side) of layers-4, 5, and 6 sensors.

The cluster hit-time resolution was also evaluated in candidate hadronic events<sup>1</sup> using the reference event time estimated by the Central Drift Chamber (CDC) outside of the SVD. The error on the event time, about 0.7 ns, was subtracted to evaluate the intrinsic SVD hit-time resolution. The resulting resolution is 2.9 ns on the u/p-side and 2.4 ns on the v/n-side. With such precise hit-time information, it is possible to reject offtime background hits efficiently. The hit-time distributions for signal<sup>2</sup> and background<sup>3</sup> are shown in Fig. 4. The signal distribution has a narrow peak, while the background hit-time distribution is broad and almost flat in the signal peak region. The separation power of the hit-time is high, as expected. For example, if we reject hits with the hit-time less than -38 ns in this plot, we can reject 45% of the background hits while keeping 99% of the signal hits. The background rejection based on the hit-time is essential to sustain the good tracking performance in the future high beam background condition.

The performance in three-samples data was compared with that in six-samples data to evaluate the performance in the

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<sup>&</sup>lt;sup>1</sup>The events with more than three good tracks and not like Bhabha scattering.

<sup>&</sup>lt;sup>2</sup>The clusters found to be used in the tracks in the hadronic events.

<sup>&</sup>lt;sup>3</sup>The clusters in events triggered by delayed-Bhabha pseudo-random trigger.

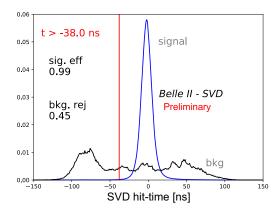


Figure 4: Example of the background hit rejection using hit-time. The blue distribution shows the signal, and the black distribution shows the background. Assuming the hit-time cut at -38 ns, the signal hit efficiency of 99% and the background hit rejection of 45% are achieved.

mixed-mode. If the trigger timing has no deviation, the three-201 165 samples data will show comparable performance to the six-202 166 samples data because the relevant part of the signal waveform203 167 to evaluate the necessary signal properties, which are the signal<sup>204</sup> 168 height and the signal timing, can be accommodated in the three-205 169 sample's time window. However, when the trigger has a jitter206 170 and the timing shift happens, some part of the signal waveform<sup>207</sup> 171 can be out of the three-sample's time window, and the recon-208 172 struction performance deteriorates. We examined the effect on<sub>209</sub> 173 the hit efficiency as a function of the trigger timing shift. The<sub>210</sub> 174 effect is evaluated by the relative hit efficiency, which is defined<sub>211</sub> 175 as the ratio of the hit efficiency in the three-samples data to the212 176 one in the six-samples data. For this study, the three-samples<sub>213</sub> 177 data are emulated in the offline analysis from the six-samples<sub>214</sub> 178 data by selecting consecutive three samples at a fixed latency<sub>215</sub> 179 with respect to the L1 trigger signal. The trigger timing  $shift_{216}$ 180 is evaluated by the CDC event time. The resulting relative effi-217 181 ciencies as a function of the trigger timing shift in the hadronic<sub>218</sub> 182 events are shown in Fig. 5. The decreasing trend is observed for  $_{210}$ 183 the shift of the trigger timing, as expected. As a result, the rel-220 184 ative efficiency is over 99.9% for the trigger timing shift within<sub>221</sub> 185  $\pm 30$  ns, which is almost all the events. 186 222

### 187 4. Beam-related background effects on SVD

The beam-related background increases the hit occupancy<sup>226</sup> 188 of the SVD, which in turn degrades the tracking performance.227 189 Considering this performance degradation, we set the occu-228 190 pancy limit in layer-3 sensors to be about 3%, which will be229 191 loosened roughly by a factor of two after we apply the hit-230 192 time rejection described in Sec. 3. With the current luminosity,231 193 the average hit occupancy in layer-3 sensors is less than 0.5%.232 194 However, the projection of the hit occupancy at the luminos-233 195 ity of  $8 \times 10^{35}$  cm<sup>-2</sup>s<sup>-1</sup> is about 3% in layer-3 sensors. The<sub>234</sub> 196 projected occupancy comes from the Monte Carlo (MC) sim-235 197 ulation scaled by the data/MC ratio determined from the beam236 198 background data of the current beam optics. The corresponding237 199 dose is about 0.2 Mrad/smy, and the equivalent 1-MeV neutron<sub>238</sub> 200

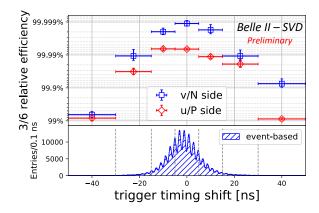


Figure 5: The relative hit efficiencies (the ratios of the hit efficiency in the threesamples data to the one in the six-samples data) as a function of the trigger timing shift for v/n-side (blue square) and u/p-side (red diamond). The positive (negative) trigger timing shift corresponds to early (late) trigger timing.

fluence is about  $5 \times 10^{11} n_{eq}/cm^2/smy$  (smy: Snowmass Year =  $10^7$  sec). The long-term extrapolation of the beam background is affected by large uncertainties from the optimization of collimator settings in MC and the future evolution of the beam injection background, which is not simulated. This uncertainty motivates the VXD upgrade which improves the tolerance of the hit rates and the radiation damage, and the technology assessment is ongoing for multiple sensor options.

From the measured dose on diamond sensors, the integrated radiation dose in the layer-3 mid-plane sensors, which are the most exposed in the SVD, is estimated to be 70 krad. The estimation is based on the correlation between the SVD occupancy and the diamonds dose. The estimated dose includes uncertainties of about 30% due to the unavailability of the appropriate trigger before December 2020. Assuming the dose/n<sub>eq</sub> fluence ratio of  $2.3 \times 10^9 \text{ n}_{eq}/\text{cm}^2/\text{krad}$  from MC, 1-MeV equivalent neutron fluence is evaluated to be about  $1.6 \times 10^{11} \text{ n}_{eq}/\text{cm}^2$  in the first two and a half years.

The effect of the integrated dose on the sensor leakage current is measured, and the results show a clear linear correlation as in the upper plot of Fig. 6. The slopes for all the sensors are summarized in the lower plot of Fig. 6. They are around 2–  $5 \,\mu$ A/cm<sup>2</sup>/Mrad. The large variations can be explained by temperature effects and the deviation of sensor-by-sensor dose from the average in each layer used in the estimation. The slopes are in the same order of magnitude as previously measured in the BaBar experiment [8], 1  $\mu$ A/cm<sup>2</sup>/Mrad at 20°C. While the leakage current is increasing, the impact on the strip noise is suppressed by the short shaping time (50 ns) in APV25. It is expected to be comparable to the strip-capacitive noise only after 10 Mrad irradiation and not problematic for ten years where the integrated dose is estimated to be 2 Mrad.

The relation between the noise and the integrated dose is shown in Fig. 7. The noise increase of 20–25% is observed in layer 3, but this does not affect the SVD performance. This noise increase is likely due to the radiation effects on the sensor surface. Fixed oxide charges on sensor surface increase nonlinearly, enlarging inter-strip capacitance. The noise saturation

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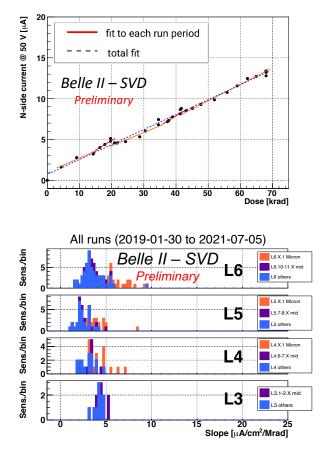


Figure 6: (upper) Effect of the integrated dose on the leakage current in the<sub>271</sub> n/v-side of one layer-3 sensor. The slope is fitted for each run period (solid red<sub>272</sub> line) and for all the runs (dashed blue line). Both fit results agree with each other and are consistent with the linear increase. (lower) The fit results of all<sup>273</sup> the sensors for all runs. The sensors are classified as trapezoidal sensors in the forward region (Micron), sensors around the midplane, and the others.

is observed on the v/n-side and also starts to be seen on the
 u/p-side. This behavior agrees with the increase of fixed oxide
 charges.

The full depletion voltage of the sensor is also a key property<sup>279</sup> 242 that can be affected by the radiation damage. It can be measured<sub>281</sub> 243 from the v/n-side strip noise, which suddenly decreases at the282 244 full depletion voltage because the sensor substrate is n-type and<sup>283</sup> 245 thus the v/n-side strips can be fully isolated at the full deple- $\frac{284}{285}$ 246 tion. From this measurement, reasonable full depletion volt-286 247 ages, which are consistent with the values mentioned in Sec. 2,287 248 were confirmed, and so far no change in full depletion voltage<sup>288</sup> 249 is observed in the first two and a half years of operation, which 250 is consistent with the expectation from low integrated neutron<sub>291</sub> 251 fluence of  $1.6 \times 10^{11} \text{ n}_{eq}/\text{cm}^2$ . 292 252

### 253 5. Conclusions

The SVD has been taking data in Belle II since March 2019 smoothly and reliably. The detector performance is excellent and agrees with expectations. We are ready to cope with the increased background during higher luminosity running by rejecting the off-time background hits using hit-time and operat-

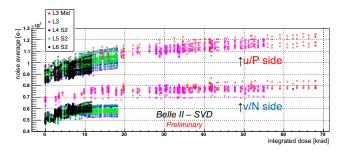


Figure 7: Effect of the integrated dose on the noise average in electron. The clear increase is observed and saturated (or start to be saturated) for layer-3 sensors.

ing in the three/six-mixed acquisition mode. In the recent study, the efficiency loss in the three-samples data is confirmed to be less than 0.1% for the trigger timing shift within ±30 ns. The observed first effects of radiation damage are also within expectation and do not affect the detector performance.

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